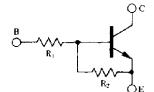


COMPOUND TRANSISTOR BA1L3M

on-chip resistor NPN silicon epitaxial transistor For mid-speed switching

FEATURES

· On-chip bias resistor $(R_1 = 4.7 \text{ k}\Omega, R_2 = 4.7 \text{ k}\Omega)$



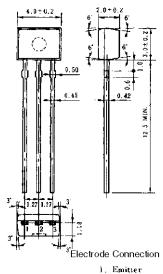
• Complementary transistor with BN1L3M

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

| Parameter | Symbol | Ratings | Unit |
|------------------------------|------------------|-------------|------|
| Collector to base voltage | Vсво | 60 | V |
| Collector to emitter voltage | VCEO | 50 | V |
| Emitter to base voltage | VEBO | 10 | V |
| Collector current (DC) | Ic(DC) | 100 | mA |
| Collector current (Pulse) | Ic(pulse) * | 200 | mA |
| Total power dissipation | Рт | 250 | mW |
| Junction temperature | Tj | 150 | °C |
| Storage temperature | T _{stg} | -55 to +150 | °C |

^{*} PW \leq 10 ms, duty cycle \leq 50 %

PACKAGE DRAWING (UNIT: mm)



- 2. Collector
- 3. Base

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

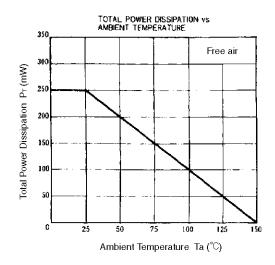
| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|------------------------------|--------------------------------|--|------|------|------|------|
| Collector cutoff current | Ісво | Vcb = 50 V, IE = 0 | | | 100 | nA |
| DC current gain | h _{FE1} ** | VcE = 5.0 V, Ic = 5.0 mA | 20 | 40 | 80 | _ |
| DC current gain | h _{FE2} ** | VcE = 5.0 V, Ic = 50 mA | 70 | 140 | | _ |
| Collector saturation voltage | VCE(sat) ** | $I_{C} = 5.0 \text{ mA}, I_{B} = 0.25 \text{ mA}$ | | 0.08 | 0.3 | V |
| Low level input voltage | VIL ** | $V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$ | | 1.1 | 0.2 | V |
| High level input voltage | V _{IH} ** | VcE = 0.2 V, Ic = 5.0 mA | 3.0 | 1.5 | | V |
| Input resistance | R ₁ | | 3.29 | 4.7 | 6.11 | kΩ |
| Resistance ratio | R ₁ /R ₂ | | 0.9 | 1.0 | 1.1 | _ |
| Turn-on time | ton | $Vcc = 5 \text{ V}, \text{ RL} = 1 \text{ k}\Omega$ | | | 0.5 | μs |
| Storage time | t _{stg} | $V_1 = 5 \text{ V}, \text{ PW} = 2 \mu \text{s}$ | | | 3.0 | μs |
| Turn-off time | toff | duty cycle≤2 % | | | 5.0 | μs |

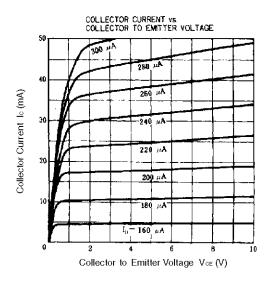
^{**} PW \leq 350 μ s, duty cycle \leq 2 %

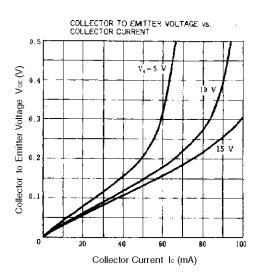
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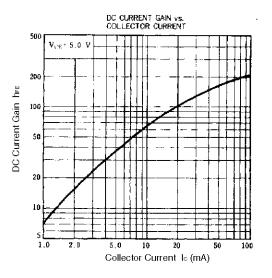


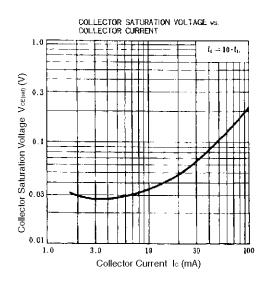
TYPICAL CHARACTERISTICS (Ta = 25°C)

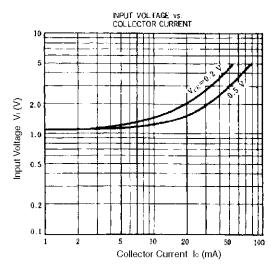


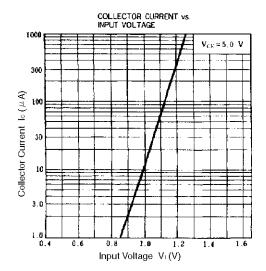


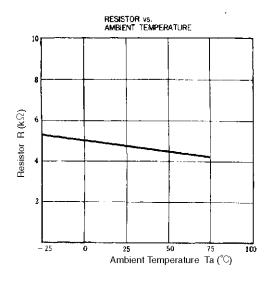












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